Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

Between 0.230 inches and 0.300 inches

Terminal Length:

Between 1.000 inches and 1.500 inches

Overall Diameter:

Between 0.085 inches and 0.130 inches

Mounting Method:

Terminal

Terminal Circle Diameter:

Between 0.018 inches and 0.022 inches

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1.50 forward voltage, dc

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current preset and 50.00 microamperes forward current, average peak

Power Rating Per Characteristic:

0.4 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Electrostatic sensitive device; hardness critical item

Nuclear Hardness Critical Feature:

Hardened

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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